

- Ideal for 980.0 MHz FCC Part 15 Transmitters
- Very Low Series Resistance
- Quartz Stability
- Surface-Mount Ceramic Case with 21 mm<sup>2</sup> Footprint
- Complies with Directive 2002/95/EC (RoHS)

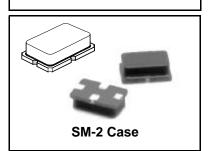
The RO2173A is a true one-port, surface-acoustic-wave (SAW) resonator in a surface-mount ceramic case. It provides reliable, fundamental-mode stabilization of fixed-frequency transmitters operating at 980.0 MHz. This SAW is designed specifically for remote-control and data-link transmitters operating in the USA under FCC Part 15 regulations.

#### **Absolute Maximum Ratings**

7.1000.000							
Rating	Value	Units					
CW RF Power Dissipation (See Typical Test Circuit)	+0	dBm					
DC Voltage Between Terminals (Observe ESD Precautions)	±30	VDC					
Case Temperature <sup>1</sup>	-40 to +85	°C					
Soldering Temperature (10 seconds / 5 cycles max.)	260	°C					

## RO2173A RO2173A-1 RO2173A-2

## 980.0 MHz SAW Resonator



#### **Electrical Characteristics**

Ch	aracteristic	Sym	Notes	Minimum	Typical	Maximum	Units
Frequency (+25 °C) Nomina	al Frequency RO2173A			979.825		980.175	
	RO2173A-1	f <sub>C</sub>		979.650		980.350	MHz
	RO2173A-2		2, 3, 4, 5	979.500		980.500	
Tolerance from 980.0 MHz RO2173A			2, 3, 4, 3			±175	
	RO2173A-1	$\Delta f_{C}$				±350	kHz
	RO2173A-2					±500	
Insertion Loss		IL	2, 5, 6			2.5	dB
Quality Factor	Unloaded Q	Q <sub>U</sub>	5, 6, 7		23,509		
	50 $Ω$ Loaded $Q$	$Q_L$	5, 0, 7		4,000		
Temperature Stability	Turnover Temperature	T <sub>O</sub>		10	25	40	°C
	Turnover Frequency	f <sub>O</sub>	6, 7, 8				MHz
	Frequency Temperature Coefficient	FTC			0.032		ppm/°C <sup>2</sup>
Frequency Aging	Absolute Value during the First Year	fA	1			50	ppm
DC Insulation Resistance between Any Two Terminals			5	1.0			ΜΩ
RF Equivalent RLC Model	Motional Resistance	$R_{M}$			20.5036		Ω
	Motional Inductance	L <sub>M</sub>	5, 6, 7, 9		83.704		μH
	Motional Capacitance	C <sub>M</sub>			0.3603		fF
	Transducer Static Capacitance	C <sub>P</sub>	5, 6, 9		2.2		pF
Test Fixture Shunt Inductance		L <sub>TEST</sub>	2, 7		13.7		nH
Lid Symbolization		287					

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### CAUTION: Electrostatic Sensitive Device. Observe precautions for handling. Notes:

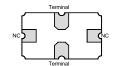
- Frequency aging is the change in f<sub>C</sub> with time and is specified at +65°C or less.
  Aging may exceed the specification for prolonged temperatures above +65°C.
  Typically, aging is greatest the first year after manufacture, decreasing in subsequent years.
- The center frequency, f<sub>C</sub>, is measured at the minimum insertion loss point, IL<sub>MIN</sub>, with the resonator in the 50 Ω test system (VSWR ≤ 1.2:1). The shunt inductance, L<sub>TEST</sub>, is tuned for parallel resonance with C<sub>O</sub> at f<sub>C</sub>. Typically, f<sub>OS-CILLATOR</sub> or f<sub>TRANSMITTER</sub> is approximately equal to the resonator f<sub>C</sub>.
- One or more of the following United States patents apply: 4,454,488 and 4,616.197.
- Typically, equipment utilizing this device requires emissions testing and government approval, which is the responsibility of the equipment manufacturer.
- 5. Unless noted otherwise, case temperature  $T_C = +25^{\circ}C \pm 2^{\circ}C$ .
- 6. The design, manufacturing process, and specifications of this device are subject

- to change without notice.
- Derived mathematically from one or more of the following directly measured parameters: f<sub>C</sub>, IL, 3 dB bandwidth, f<sub>C</sub> versus T<sub>C</sub>, and C<sub>O</sub>.
- Turnover temperature, T<sub>O</sub>, is the temperature of maximum (or turnover) frequency, f<sub>O</sub>. The nominal frequency at any case temperature, T<sub>C</sub>, may be calculated from: f = f<sub>O</sub> [1 FTC (T<sub>O</sub> -T<sub>C</sub>)<sup>2</sup>]. Typically oscillator T<sub>O</sub> is approximately equal to the specified resonator T<sub>O</sub>.
- 3. This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance  $C_0$  is the static (nonmotional) capacitance between the two terminals measured at low frequency (10 MHz) with a capacitance meter. The measurement includes parasitic capacitance with "NC" pads unconnected. Case parasitic capacitance is approximately 0.05 pF. Transducer parallel capacitance can by calculated as:  $C_P \approx C_0 0.05$  pF.

### SAW Resonator

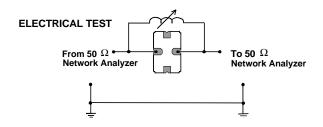
#### **Electrical Connections**

The SAW resonator is bidirectional and may be installed with either orientation. The two terminals are interchangeable and unnumbered. The callout NC indicates no internal connection. The NC pads assist with mechanical positioning and stability. External grounding of the NC pads is recommended to help reduce parasitic capacitance in the circuit

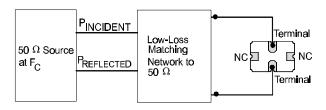


#### **Typical Test Circuit**

The test circuit inductor,  $L_{\text{TEST}}$ , is tuned to resonate with the static capacitance,  $C_{\text{O}}$ , at  $F_{\text{C}}$ .

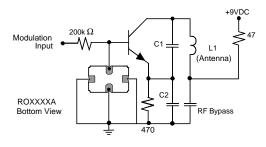


#### **POWER TEST**

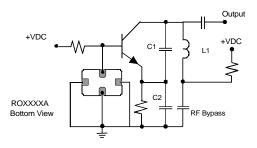


CW RF Power Dissipation = P<sub>INCIDENT</sub> - P<sub>REFLECTED</sub> **Typical Application Circuits** 

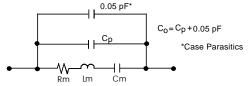
#### Typical Low-Power Transmitter Application



#### **Typical Local Oscillator Application**

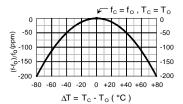


#### **Equivalent LC Model**



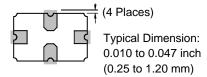
#### **Temperature Characteristics**

The curve shown on the right accounts for resonator contribution only and does not include LC component temperature contributions.



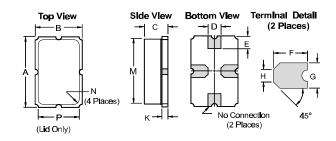
# Typical Circuit Board Land Pattern

The circuit board land pattern shown below is one possible design. The optimum land pattern is dependent on the circuit board assembly process which varies by manufacturer. The distance between adjacent land edges should be at a maximum to minimize parasitic capacitance. Trace lengths from terminal lands to other components should be short and wide to minimize parasitic series inductances.



#### **Case Design**

The case material is black alumina with contrasting symbolization. All pads are nominally centered with respect to the base and consist of 40 to 70 microinches electroless gold on 60-350 microinches electroless nickel.



Dimensions	Millimeters		Inches		
	Min	Max	Min	Max	
A	5.74	5.99	0.226	0.236	
В	3.73	3.99	0.147	0.157	
С	1.91	2.16	0.075	0.085	
D	0.94	1.10	0.037	0.043	
Е	0.83	1.20	0.033	0.047	
F	1.16	1.53	0.046	0.060	
G	0.94	1.10	0.037	0.043	
Н	0.43	0.59	0.017	0.023	
K	0.43	0.59	0.017	0.023	
М	5.08	5.33	0.200	0.210	
N	0.38	0.64	0.015	0.025	
Р	3.05	3.30	0.120	0.130	